SOD-123 Schottky Barrier Diodes

MMSD301T1G, SMMSD301T1G, MMSD701T1G, SMMSD701T1G,

The MMSD301T1, and MMSD701T1 devices are spin-offs of our popular MMBD301LT1, and MMBD701LT1 SOT-23 devices. They are designed for high-efficiency UHF and VHF detector applications. Readily available to many other fast switching RF and digital applications.

Features

- Extremely Low Minority Carrier Lifetime
- Very Low Capacitance
- Low Reverse Leakage
- AEC Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage MMSD301T1G, SMMSD301T1G MMSD701T1G, SMMSD701T1G	V _R	30 70	Vdc
Forward Current (DC) Continous	IF	200	mA
Forward Power Dissipation T _A = 25°C	P _F	225	mW
Junction Temperature	TJ	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



ON Semiconductor®

www.onsemi.com



SOD-123 CASE 425 STYLE 1



MARKING DIAGRAM



xx = Specific Device Code XT = MMSD301T1G SMMSD301T1G XH = MMSD701T1G

SMMSD70111G - Date Code

M = Date Code= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
MMSD301T1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel
SMMSD301T1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel
MMSD701T1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel
SMMSD701T1G	SOD-123 (Pb-Free)	3,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

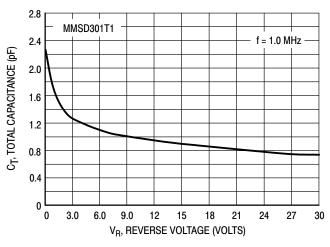
${\bf MMSD301T1G,\,SMMSD301T1G,\,MMSD701T1G,\,SMMSD701T1G,}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I _R = 10 μA) MMSD301T1G, SMMSD301T1G	V _{(BR)R}	30	-	-	V
MMSD701T1G, SMMSD701T1G		70	-	_	
Diode Capacitance (V _B = 0 V, f = 1.0 MHz)	C _T				pF
MMSD301T1G, SMMSD301T1G MMSD701T1G, SMMSD701T1G		- -	0.9 0.5	1.5 1.0	
Total Capacitance	C _T				pF
(V _R = 15 V, f = 1.0 MHz) MMSD301T1G, SMMSD301T1G (V _R = 20 V, f = 1.0 MHz)		_	0.9	1.5	
MMSD701T1G, SMMSD701T1G		-	0.5	1.0	
Reverse Leakage	I _R				nAdc
$(V_R = 25 \text{ V})$ MMSD301T1G, SMMSD301T1G $(V_R = 35 \text{ V})$		-	13	200	
MMSD701T1G, SMMSD701T1G		-	9.0	200	
Forward Voltage (I _F = 1.0 mAdc)	V _F				Vdc
MMSD301T1G, SMMSD301T1G (I _F = 10 mA) (I _F = 1.0 mAdc)		-	0.38 0.52	0.45 0.6	
MMSD701T1G, SMMSD701T1G (I _F = 10 mA)		- -	0.42 0.7	0.5 1.0	

MMSD301T1G, SMMSD301T1G, MMSD701T1G, SMMSD701T1G,

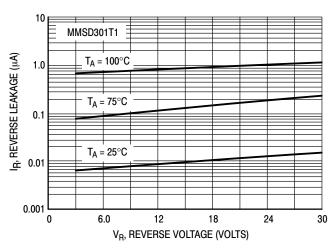
TYPICAL CHARACTERISTICS MMSD301T1G, SMMSD301T1G



500 MMSD301T1 WH 400 KRAKAUER METHOD KRAKAUER METHOD 100 100 100 20 30 40 50 60 70 80 90 100 15 FORWARD CURRENT (mA)

Figure 1. Total Capacitance

Figure 2. Minority Carrier Lifetime



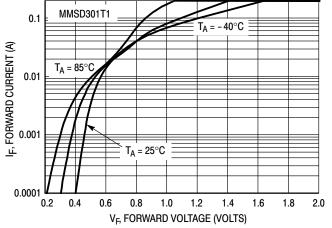


Figure 3. Reverse Leakage

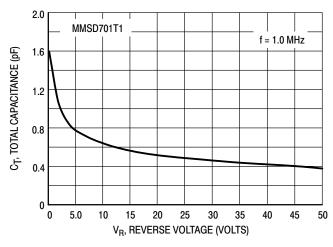
Figure 4. Forward Voltage

MMSD301T1G, SMMSD301T1G, MMSD701T1G, SMMSD701T1G,

TYPICAL CHARACTERISTICS MMSD701T1G, SMMSD701T1G

100

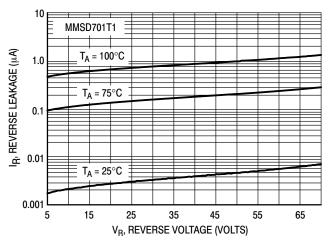
MMSD701T1



500 MMSD701T1 τ , MINORITY CARRIER LIFETIME (ps) 400 KRAKAUER METHOD 300 200 100 0 10 20 30 40 50 70 80 90 100 I_{F.} FORWARD CURRENT (mA)

Figure 5. Total Capacitance

Figure 6. Minority Carrier Lifetime



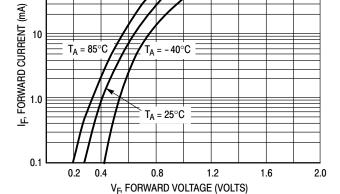


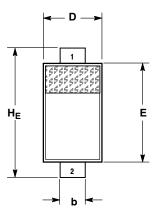
Figure 7. Reverse Leakage

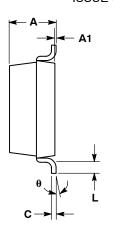
Figure 8. Forward Voltage

MMSD301T1G, SMMSD301T1G, MMSD701T1G, SMMSD701T1G,

PACKAGE DIMENSIONS

SOD-123 CASE 425-04 **ISSUE G**



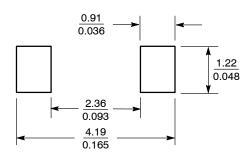


- 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS					
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.94	1.17	1.35	0.037	0.046	0.053
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.51	0.61	0.71	0.020	0.024	0.028
С			0.15			0.006
D	1.40	1.60	1.80	0.055	0.063	0.071
E	2.54	2.69	2.84	0.100	0.106	0.112
HE	3.56	3.68	3.86	0.140	0.145	0.152
L	0.25			0.010		
θ	0°		10°	0°		10°

STYLE 1: PIN 1. CATHODE 2. ANODE

SOLDERING FOOTPRINT*



SCALE 10:1

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and IN are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability. arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.

Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative